

1201.63407

PATENT APPLICATION

2811  
Jhw

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE



Applicant: Munir H. Nayfeh  
Serial No.: 09/496,506  
Conf. No.: 6344  
Filed: February 2, 2000  
For: SILICON NANOPARTICLE FIELD  
EFFECT TRANSISTOR AND  
TRANSISTOR MEMORY DEVICE  
Art Unit: 2811  
Examiner: Sara W. Crane

I hereby certify that this paper is being deposited with the United States Postal Service as FIRST-CLASS mail in an envelope addressed to: Mail Stop AMENDMENT, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on this date.

December 29, 2004

*A. B. R.*

Date

Registration No. 43,874

F-CLASS.WCM

Appr. February 20, 1998

Attorney for Applicant

Mail Stop AMENDMENT  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

TRANSMITTAL

Dear Sir:

Enclosed please find the following:

(X) Response H.

(X) Declaration of Munir Nayfeh.

(X) Petition for Extension of Time (in duplicate), with a check in the amount of \$510.00.

(X) If a Petition under 37 C.F.R. §1.136(a) for an extension of time for response is required to make the attached response timely and does not separately accompany this transmittal, Applicant(s) hereby petition(s) under 37 C.F.R. §1.136(a) for an extension of time for response in the above-identified application for the period required to make the attached response timely.

(X) The Commissioner is hereby authorized to charge any additional fees which may be required to this application under 37 C.F.R. §§1.16-1.17, or credit any overpayment, to Deposit Account No. 07-2069. A duplicate copy of this sheet is enclosed.

Customer No. 24978

December 29, 2004

300 South Wacker Drive - Suite 2500  
Chicago, Illinois 60606  
Tel: (312) 360-0080  
Fax: (312) 360-9315  
P:\DOCS\1201\63407\795738.DOC

Respectfully submitted,

GREER, BURNS & CRAIN, LTD.

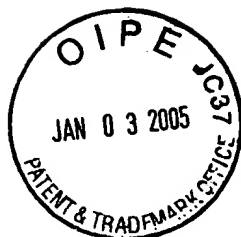
By:

*A. B. R.*

Arik B. Ranson

Registration No. 43,874

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A handwritten signature in black ink, appearing to be "A. B. R.", written over a horizontal line.

Date

Registration No. 43,874

F-CLASS.WCM

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Attorney for Applicant

### RESPONSE H

Mail Stop AMENDMENT  
Commissioner of Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

In response to the Office Action mailed June 29, 2004, please consider the following remarks: